

ST13009

High voltage fast-switching NPN power transistor

Features

- Low spread of dynamic parameters
- High voltage capability
- Minimum lot-to-lot spread for reliable operation
- Very high switching speed

Applications

■ Switch mode power supplies

Description

The device is manufactured using high voltage multi-epitaxial planar technology for high switching speeds and high voltage capability. It uses a hollow emitter structure to enhance switching speeds.

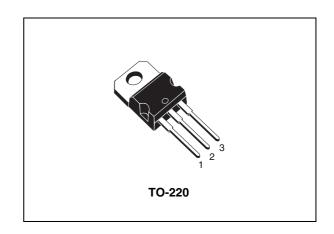


Figure 1. Internal schematic diagram

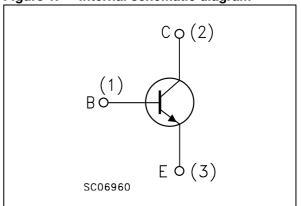


Table 1. Device summary

Order code	Marking ⁽¹⁾	Package	Packaging
ST13009	13009 L 13009 H	TO-220	Tube

^{1.} Product is pre-selected in DC current gain (group L and group H). STMicroelectronics reserves the right to ship either groups according to production availability. Please contact your nearest STMicroelectronics sales office for delivery details.

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ST13009 Electrical ratings

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CEV}	Collector-emitter voltage (V _{BE} = -1.5 V)	700	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	400	V
V _{EBO}	Emitter-base voltage (I _C = 0)	12	V
I _C	Collector current	12	Α
I _{CM}	Collector peak current (t _P < 5ms)	24	Α
I _B	Base current	6	Α
I _{BM}	Base peak current (t _P < 5ms)	12	Α
P _{tot}	Total dissipation at T _c = 25°C	100	W
T _{stg}	Storage temperature	-65 to 150	°C
TJ	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{thj-case}	Thermal resistance junction-case Max	1.25	°C/W

Electrical characteristics ST13009

2 Electrical characteristics

 $(T_{case} = 25^{\circ}C \text{ unless otherwise specified})$

Table 4. Electrical characteristics

Symbol	Parameter	Test co	Min.	Тур.	Max.	Unit	
I _{CEV}	Collector cut-off current (V _{BE} = -1.5 V)	V _{CE} = 700 V V _{CE} = 700 V	T _C = 100°C			10 500	μ Α μ Α
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = 10 V				10	μА
V _{CEO(sus)} (1)	Collector-emitter sustaining voltage (I _B = 0)	I _C = 10 mA		400			V
		I _C = 4 A	$I_B = 0.8 A$			0.85	V
V _{CE(sat)} (1)	Collector-emitter	$I_C = 5 A$	$I_B = 1 A$			0.9	V
OE(Sai)	saturation voltage	_	$I_B = 1.6 A$			1.25	V
		I _C = 12 A	$I_B = 3 A$			2.5	V
(1)	Base-emitter saturation	$I_C = 5 A$	$I_B = 1 A$			1.2	V
V _{BE(sat)} (1)	voltage	$I_C = 8 A$	$I_{B} = 1.6 A$			1.6	V
		I _C = 5 A	V _{CE} = 5 V				
h _{FE} (1)(2)	DC ourrent gain	Group L		15		31	
I'FE`'\	DC current gain	Group H		26		39	
		$I_C = 8 A$	$V_{CE} = 5 V$	10		30	
		I _C = 5 A	V _{CC} = 250 V				
	Inductive load	I _{B1} = 1 A	$I_{B2} = -2 A$				
t _s	Storage time	L = 200 μH			1.6	2.5	μs
t _f	Fall time	see <i>Figure 9</i>			60	110	ns
	landa aktiva land	I _C = 5 A	V _{CC} = 125 V				
t _s	Inductive load Storage time Fall time	$I_{B1} = -I_{B2} = 1$ $L = 200 \mu H$ see <i>Figure 9</i>	.6 A $t_c = 125 ^{\circ}\text{C}$		2.3 110		μs ns

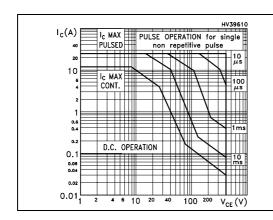
^{1.} Pulsed duration = 300 μ s, duty cycle \leq 2 %

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2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

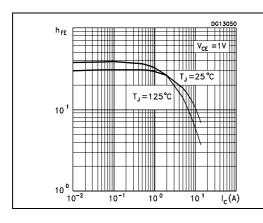
Figure 3. Derating curve



P_{tot} (%)
100
80
60
40
20
0 25 50 75 100 125 T_{case}(°C)

Figure 4. DC current gain

Figure 5. DC current gain



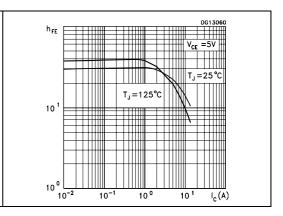
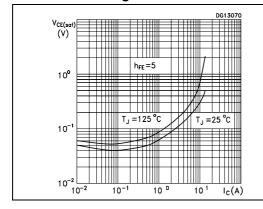
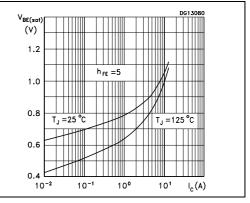


Figure 6. Collector-emitter saturation voltage

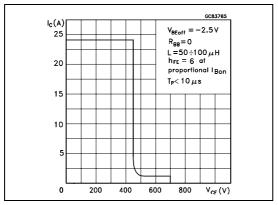
Figure 7. Base-emitter saturation voltage





Electrical characteristics ST13009

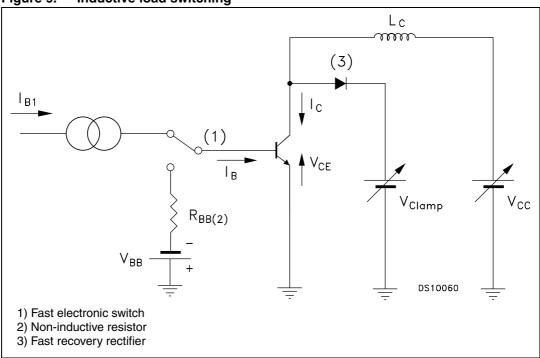
Figure 8. Reverse biased operating area



ST13009 Test circuit

3 Test circuit

Figure 9. Inductive load switching



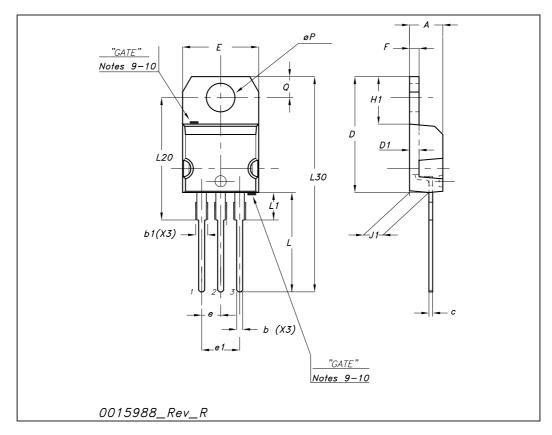
4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

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TO-220 mechanical data

Dim		mm			inch			
	Min	Тур	Max	Min	Тур	Max		
А	4.40		4.60	0.173		0.181		
b	0.61		0.88	0.024		0.034		
b1	1.14		1.70	0.044		0.066		
С	0.48		0.70	0.019		0.027		
D	15.25		15.75	0.6		0.62		
D1		1.27			0.050			
E	10		10.40	0.393		0.409		
е	2.40		2.70	0.094		0.106		
e1	4.95		5.15	0.194		0.202		
F	1.23		1.32	0.048		0.051		
H1	6.20		6.60	0.244		0.256		
J1	2.40		2.72	0.094		0.107		
L	13		14	0.511		0.551		
L1	3.50		3.93	0.137		0.154		
L20		16.40			0.645			
L30		28.90	ĺ		1.137			
ØP	3.75		3.85	0.147		0.151		
Q	2.65		2.95	0.104		0.116		



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Revision history ST13009

5 Revision history

Table 5. Document revision history

Date	Revision	Changes
12-Jun-2005	1	First version
23-Aug-2007	2	Added figures: 2, and 3
30-Jun-2009	3	Updated value for h _{FE} see <i>Table 4: Electrical characteristics</i>

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